

Title (en)
SEMICONDUCTOR DEVICE

Title (de)
HALBLEITERBAUELEMENT

Title (fr)
DISPOSITIF À SEMI-CONDUCTEUR

Publication
EP 3036762 A1 20160629 (EN)

Application
EP 14837815 A 20140326

Priority
• KR 20130099144 A 20130821
• KR 2014002579 W 20140326

Abstract (en)
[origin: US2015054019A1] A semiconductor device includes an electrode including a plurality of pillars, a semiconductor element configured to be electrically-connected with the electrode, a substrate having electrode patterns, and a conductive adhesive layer located between the substrate and the electrode, the conductive adhesive layer including conductive substances configured to electrically-connect the pillars and the electrode patterns to each other, and including a body which encloses the conductive substances.

IPC 8 full level
H01L 23/48 (2006.01); **H01L 23/492** (2006.01); **H01L 33/62** (2010.01)

CPC (source: EP KR US)
C09J 9/02 (2013.01 - US); **H01L 23/48** (2013.01 - KR); **H01L 24/29** (2013.01 - EP US); **H01L 24/83** (2013.01 - EP US); **H01L 33/62** (2013.01 - EP US); **C09J 2301/314** (2020.08 - EP US); **H01L 23/4828** (2013.01 - US); **H01L 23/4922** (2013.01 - US); **H01L 23/5328** (2013.01 - US); **H01L 24/32** (2013.01 - EP US); **H01L 24/81** (2013.01 - EP US); **H01L 24/91** (2013.01 - EP US); **H01L 33/36** (2013.01 - US); **H01L 33/38** (2013.01 - US); **H01L 2224/0401** (2013.01 - EP US); **H01L 2224/1134** (2013.01 - EP US); **H01L 2224/1411** (2013.01 - EP US); **H01L 2224/2929** (2013.01 - EP US); **H01L 2224/29355** (2013.01 - EP US); **H01L 2224/29386** (2013.01 - EP US); **H01L 2224/29561** (2013.01 - EP US); **H01L 2224/29644** (2013.01 - EP US); **H01L 2224/29655** (2013.01 - EP US); **H01L 2224/81191** (2013.01 - EP US); **H01L 2224/81903** (2013.01 - EP US); **H01L 2224/83192** (2013.01 - EP US); **H01L 2224/83851** (2013.01 - EP US); **H01L 2224/9211** (2013.01 - EP US); **H01L 2225/1058** (2013.01 - US); **H01L 2924/12041** (2013.01 - EP US); **H01L 2924/156** (2013.01 - US); **H01L 2924/35** (2013.01 - US); **H01L 2924/36** (2013.01 - US); **H10K 50/8426** (2023.02 - US)

Designated contracting state (EPC)
AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO PL PT RO RS SE SI SK SM TR

Designated extension state (EPC)
BA ME

DOCDB simple family (publication)
US 2015054019 A1 20150226; **US 9252346 B2 20160202**; CN 105474376 A 20160406; CN 105474376 B 20190305;
EP 3036762 A1 20160629; EP 3036762 A4 20170322; EP 3036762 B1 20200715; KR 101513642 B1 20150420; KR 20150021770 A 20150303;
WO 2015026034 A1 20150226

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